TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

T C 7 M H 1 3 9 F K

Dual 2-To-4 Line Decoder

The TC7MH139 is an advanced high speed CMOS 2 to 4 LINE DECODER / DEMULTIPLEXER fabricated with silicon gate C2MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

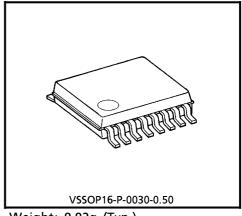
The active low enable input can be used for gating or it can be used as a data input for demultiplexing applications.

When the enable input is held High, all four outputs are fixed at a high logic level independent of the other inputs.

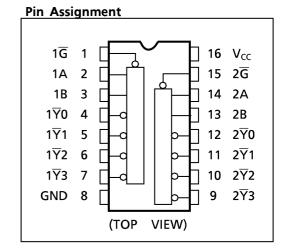
An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features:

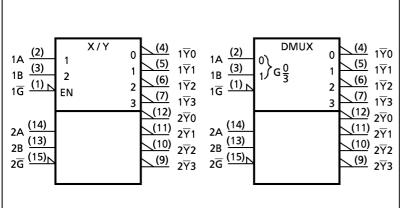
- High Speed······ t_{pd} = 5.0ns(typ.) at V_{CC} = 5V
- Low Power Dissipation ······· $I_{CC} = 4\mu A(max)$ at $Ta = 25^{\circ}C$
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (min)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays ····· t_{pLH} ≃ t_{pHL}
- Wide Operating Voltage Range ···· V_{CC} (opr) = 2V ~ 5.5V
- Pin and Function Compatible with 74ALS139



Weight: 0.02g (Typ.)



IEC Logic Symbol

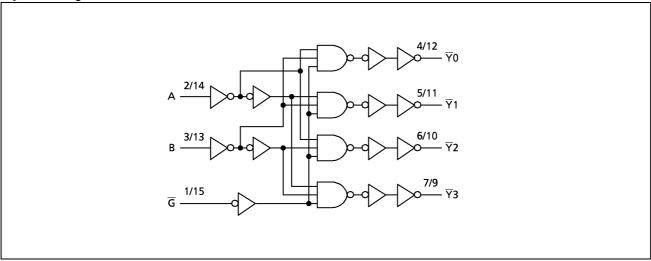


INP	C	UTI							
ENABLE	SELECT		<u></u> 70	<u>\text{Y}1</u>	∀ 2	√2	SELECTED OUTPUT		
G	В	Α	10	τl	12	13	COTPUT		
Н	Х	Х	Η	Н	Н	Н	NONE		
L	L	L	L	Η	Н	Н	∀ 0		
L	L	I	Η	L	Н	Н	<u>\(\bar{Y} \) 1</u>		
L	Н	Г	Η	Η	L	Н	₹2		
L	Η	Н	Ι	Ι	Н	L	∀ 3		

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System Diagram



Absolute Maximum Ratings

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{cc}	− 0.5~7.0	V
DC Input Voltage	V _{IN}	− 0.5~7.0	V
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	-20	mA
Output Diode Current	I _{OK}	±20	mA
DC Output Current	I _{OUT}	± 25	mA
DC V _{CC} /Ground Current	I _{cc}	± 75	mA
Power Dissipation	P _D	180	mW
Storage Temperature	T _{stg}	−65~150	°C

Recommended Operating Conditions

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{cc}	2.0~5.5	V
Input Voltage	VIN	0~5.5	V
Output Voltage	V _{OUT}	0∼V _{cc}	V
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	dt/dv	$0\sim100 \ (V_{CC} = 3.3 \pm 0.3 V)$ $0\sim20 \ (V_{CC} = 5 \pm 0.5 V)$	ns / V

1999-10-14

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DC Electrical Characteristics

PARAMETER	SYMBOL	TEST CONDITION		V _{cc}	Ta = 25°C			Ta = - 4	UNIT	
PARAIVIETER	STIVIBUL	1231 CO	(V)	Min	Тур.	Max	Min	Max	UIVIII	
High - Level	· ·			2.0	1.50	-	_	1.50	1	\ \ \ \ \ \
Input Voltage	V _{IH}			3.0~ 5.5	$V_{cc} \times 0.7$	_	_	$V_{cc} \times 0.7$	_	
Low - Level	.,			2.0	ı	-	0.50	_	0.50	.,
Input Voltage	V _{IL}		3.0~ 5.5	_	_	$V_{cc} \times 0.3$	_	$V_{cc} \times 0.3$		
	V _{OH}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -50\mu A$	2.0	1.9	2.0	_	1.9	1	
High - Level Output Voltage				3.0 4.5	2.9 4.4	3.0 4.5	_	2.9 4.4	_	v
			$I_{OH} = -4mA$ $I_{OH} = -8mA$	3.0 4.5	2.58 3.94		_	2.48 3.80		
Low - Level Output Voltage	V _{OL}	.,	. 50 4	2.0	-	0.0	0.1	_	0.1	
		V _{I N} =	$I_{OL} = 50 \mu A$	3.0 4.5	_	0.0 0.0	0.1 0.1	_	0.1 0.1	V
		V _{IH} or V _{IL}	I _{OL} = 4mA I _{OL} = 8mA	3.0 4.5		_	0.36 0.36	_	0.44 0.44	
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND		0~5.5	_	_	± 0.1	_	± 1.0	
Quiescent Supply Current	I _{cc}	$V_{IN} = V_{CC}$ or GN	5.5	1	-	4.0	_	40.0	μ A	

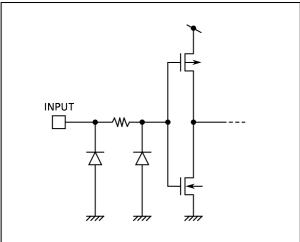
AC Electrical Characteristics (Input $t_r = t_f = 3ns$)

PARAMETER		TEST	ST CONDITION			Γa = 25°0	_	Ta = - 4	LINIT	
PARAIVIETER	SYMBOL		V _{cc} (V)	CL (pF)	Min	Тур.	Max	Min	Max	UNIT
	4		3.3 ± 0.3	15	_	7.2	11.0	1.0	13.0	ns
Propagation Delay Time (A,B - \overline{Y})	t _{pLH} t _{pHL}			50	1	9.7	14.5	1.0	16.5	
			5.0 ± 0.5	15	1	5.0	7.2	1.0	8.5	
			3.0 ± 0.3	50	1	6.5	9.2	1.0	10.5	
Propagation Delay Time $(\overline{G} - \overline{Y})$	t _{pLH} t _{pHL}		3.3 ± 0.3	15	1	6.4	9.2	1.0	11.0	
				50	_	8.9	12.7	1.0	14.5	
			5.0 ± 0.5	15	_	4.4	6.3	1.0	7.5	
				50	_	5.9	8.3	1.0	9.5	
Input Capacitance	C _{I N}				_	4	10	_	10	, r
Power Dissipation Capacitance	C _{PD}		(Note 1)	·	_	26	_	_	_	pF

(Note 1): C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

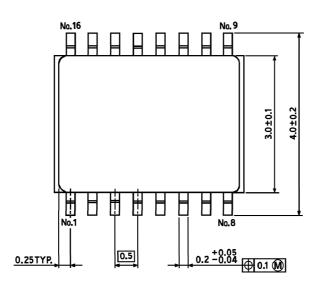
Average operating current can be obtained by the equation: $I_{CC\,(opr.)}=C_{PD}\cdot V_{CC}\cdot f_{IN}+I_{CC}/2$ (per decoder)

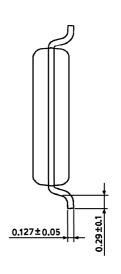
Input Equivalent Circuit



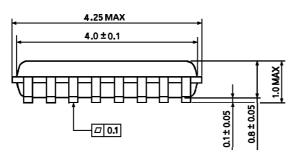
Outline Drawing

VSSOP16-P-0030-0.50





Unit: mm



Weight: 0.02g (Typ.)